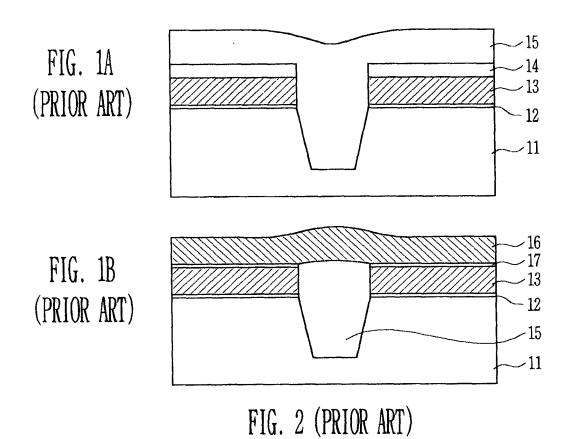
Atty. Docket No. 29936/39460

Inventors: Seung Cheol Lee, Sang Wook Park, Jung Il Cho Title: Method of Forming a Floating Gate in a Flash

Memory Cell

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Number of Cells 100k · 10k 1k 100 10 100 Threshold voltage

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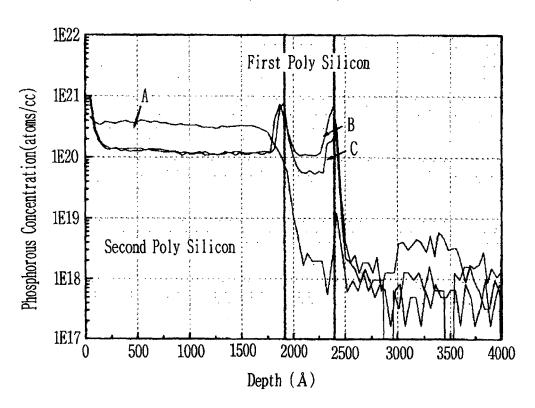
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FIG. 3 (PRIOR ART)



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25 24 23 FIG. 4A 22 **-21** Cleaning 22 FIG. 4B 25 -21 Decomposition + Anneal + Deposition -26 **2**3 FIG. 4C - 22 25

**√21** 

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FIG. 5

